



FZT560Q

#### 500V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

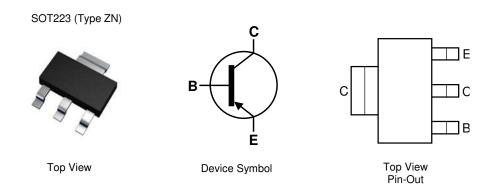
#### **Features**

- BV<sub>CEO</sub> > -500V
- I<sub>C</sub> = -150mA High Continuous Current
- I<sub>CM</sub> = -500mA Peak Pulse Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ FZT560Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

#### **Mechanical Data**

- Package: SOT223 (Type ZN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)



### Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT560QTA	Automotive	FZT560	7	12	1,000
FZT560QTC	Automotive	FZT560	13	12	4,000

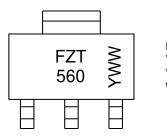
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

Notes:



FZT 560 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 2 = 2022) WW or  $\overline{W}W$  = Week Code (01~53)

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### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-500	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-500	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I <sub>CM</sub>	-500	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	Pn	2	W
Fower Dissipation	(Note 6)	FD	3	W
Thermal Desistance, lunction to Ambient	(Note 5)	P	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R <sub>ejl</sub>	14.8	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

### ESD Ratings (Note 8)

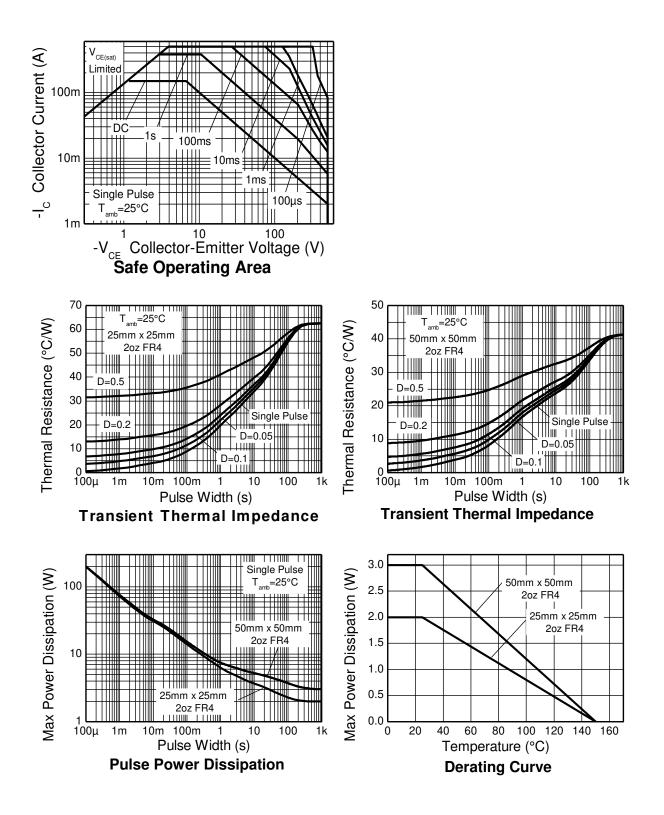
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in steady-state. 6. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

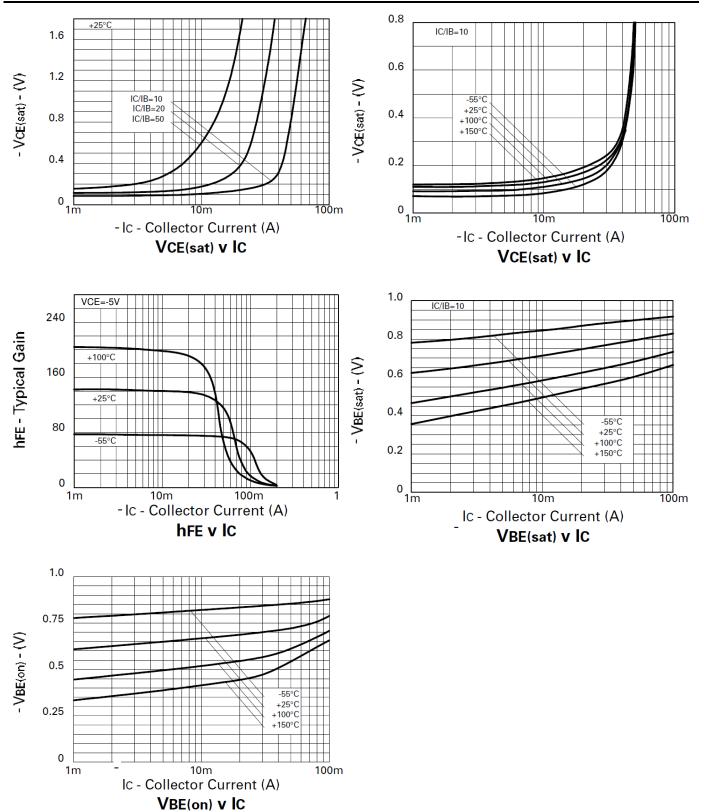
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-500	-	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-500	_	_	V	$I_{\rm C} = -1 {\rm mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I <sub>CBO</sub>	-	-	-100	nA	V <sub>CB</sub> = -500V
Collector Cut-Off Current	ICES	-	-	-100	nA	V <sub>CE</sub> = -500V
Emitter Cut-Off Current	I <sub>EBO</sub>	-	-	-100	nA	$V_{EB} = -5.6V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	-	-	-200	mV	$I_{\rm C} = -20 {\rm mA}, I_{\rm B} = -2 {\rm mA}$
Collector-Emiller Saturation Voltage (Note 9)		-	-	-500	111 V	$I_{\rm C} = -50 {\rm mA}, I_{\rm B} = -10 {\rm mA}$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	_	-900	mV	I <sub>C</sub> = -50mA, I <sub>B</sub> = -10mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	-	-900	mV	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}$
	hfe	100	-	300		$I_{C} = -1mA, V_{CE} = -10V$
DC Current Gain (Note 9)		80	-	300	_	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}$
		_	15	-		$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}$
Current Gain-Bandwidth Product	f <sub>T</sub>	60	-	-	MHz	$V_{CE} = -20V$ , $I_C = -10mA$ f = 50MHz
Turn-On Time	t <sub>on</sub>	-	110	_	ns	$V_{CC} = -100V, I_{C} = -50mA$
Turn-Off Time	t <sub>off</sub>	-	1.5	_	μs	$I_{B1} = -5mA$ , $I_{B2} = 10mA$
Output Capacitance	C <sub>obo</sub>	-	-	8	pF	V <sub>CB</sub> = -20V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 µs. Duty cycle  $\leq$  2%.



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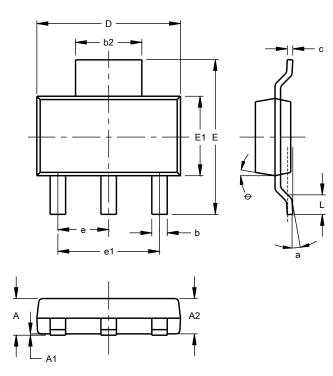
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# Package Outline Dimensions

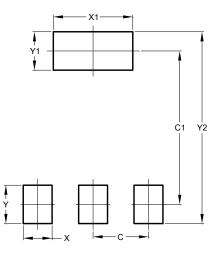
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223 (Type ZN)					
Dim	Min	Max	Тур		
Α		1.70			
A1	0.02	0.10			
A2	1.50	1.68	1.60		
b	0.60	0.80			
b2	2.90	3.10			
c	0.24	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
e	2.30 NOM				
e1	4.60 NOM				
L	0.90				
а			10°		
θ		15°			
All D	All Dimensions in mm				

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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